

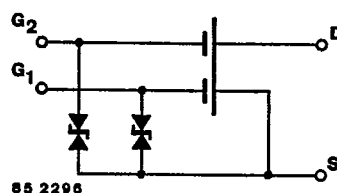
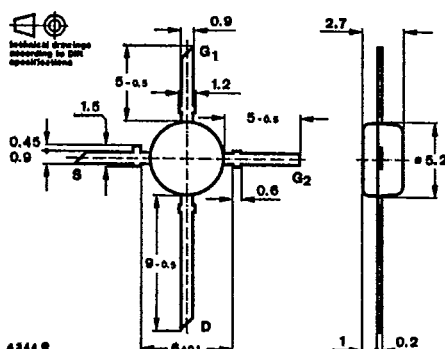


TELEFUNKEN electronic

Creative Technologies

T-31-25
BF 960**N-Channel Dual Gate MOS-Fieldeffect Tetrode · Depletion Mode****Applications:** Input- and Mixerstages especially for UHF TV-tuners up to 900 MHz**Features:**

- Integrated Gate protection diodes
- High cross modulation performance
- Low noise figure
- High AGC-range
- Low feedback capacitance
- Low input capacitance

Dimensions in mm

Case
50 B 4 DIN 41 867
JEDEC TO 50
Weight max. 0.1 g

Absolute maximum ratings

Drain Source Voltage	V_{DS}	20	V
Drain current	I_D	30	mA
Gate 1/Gate 2-Source peak current	$\pm I_{G1/2SM}$	10	mA
Total power dissipation $T_{amb} = 60^\circ\text{C}$	P_{tot}	200	mW
Channel temperature	T_C	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 ... +150	$^\circ\text{C}$

Thermal resistance

Channel ambient
mounted on pc-board one side
Cu 35 μm thickness 40 x 25 x 1.5 mm³

	Min.	Typ.	Max.
R_{thCA}			450 K/W

T1.2/330.1183 E2

3523 6-04

83

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DC characteristics

Min. Typ. Max.

 $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Drain-source breakdown voltage

 $I_D = 10\text{ }\mu\text{A}$, $-V_{G1S} = -V_{G2S} = 4\text{ V}$ $V_{(BR)DS}$

20

V

Gate 1-Source breakdown voltage

 $\pm I_{G1S} = 10\text{ mA}$, $V_{G2S} = V_{DS} = 0$ $\pm V_{(BR)G1SS}$

6

20

V

Gate 2-Source breakdown voltage

 $\pm I_{G2S} = 10\text{ mA}$, $V_{G1S} = V_{DS} = 0$ $\pm V_{(BR)G2SS}$

6

20

V

Gate 1-Source cut-off current

 $\pm V_{G1S} = 5\text{ V}$, $V_{G2S} = V_{DS} = 0$ I_{G1SS}

50

nA

Gate 2-Source cut-off current

 $\pm V_{G2S} = 5\text{ V}$, $V_{G1S} = V_{DS} = 0$ I_{G2SS}

50

nA

Drain current

 $V_{DS} = 15\text{ V}$, $V_{G1S} = 0$, $V_{G2S} = 4\text{ V}$ I_{DSS}

2

20

mA

Gate 1-Source cut-off voltage

 $V_{DS} = 15\text{ V}$, $V_{G2S} = 4\text{ V}$, $I_D = 20\text{ }\mu\text{A}$ $-V_{G1S(OFF)}$

2.7

V

Gate 2-Source cut-off voltage

 $V_{DS} = 15\text{ V}$, $V_{G1S} = 0\text{ V}$, $I_D = 20\text{ }\mu\text{A}$ $-V_{G2S(OFF)}$

2.7

V

AC characteristics

 $V_{DS} = 15\text{ V}$, $I_D = 7\text{ mA}$, $V_{G2S} = 4\text{ V}$, $f = 1\text{ MHz}$, $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Forward transadmittance

 $|y_{21}|$

10

13

mS

Gate 1-Input capacitance

 C_{ISSG1}

1.8

pF

Gate 2-Input capacitance

 $V_{G1S} = 0$, $V_{G2S} = 4\text{ V}$ C_{ISSG2}

1.0

pF

Feedback capacitance

 $C_{RSS}^{1)}$

25

fF

Output capacitance

 C_{OSS}

0.8

pF

Power gain

 $V_{DS} = 15\text{ V}$, $I_D = 7\text{ mA}$, $V_{G2S} = 4\text{ V}$, $g_G = 2\text{ mS}$, $g_L = 5\text{ mS}$, $f = 200\text{ MHz}$ G_{ps}

23

dB

 $g_L = 1\text{ mS}$, $f = 800\text{ MHz}$ G_{ps}

16.5

dB

Noise figure

 $g_G = 2\text{ mS}$, $f = 800\text{ MHz}$ F

2.2

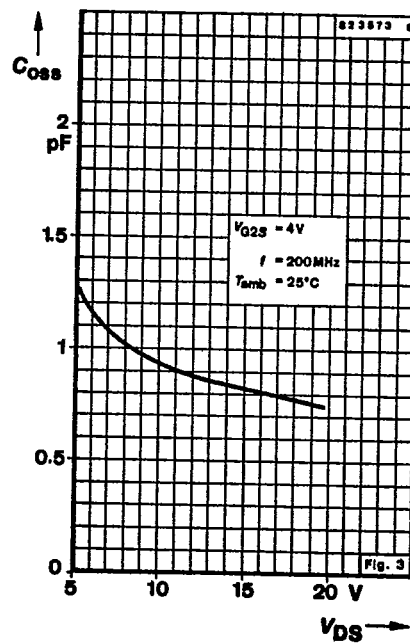
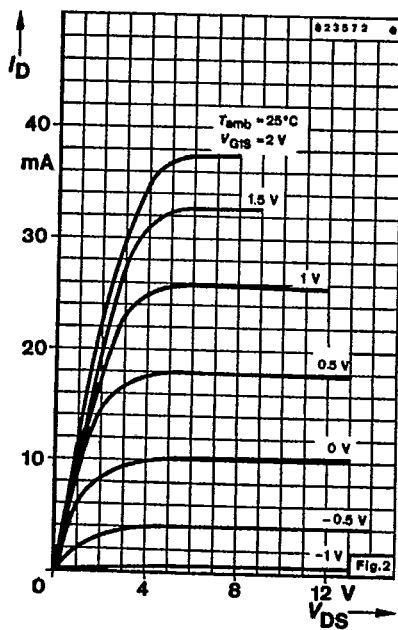
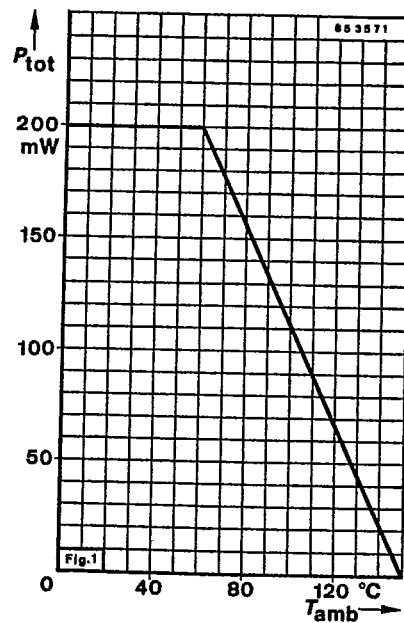
3

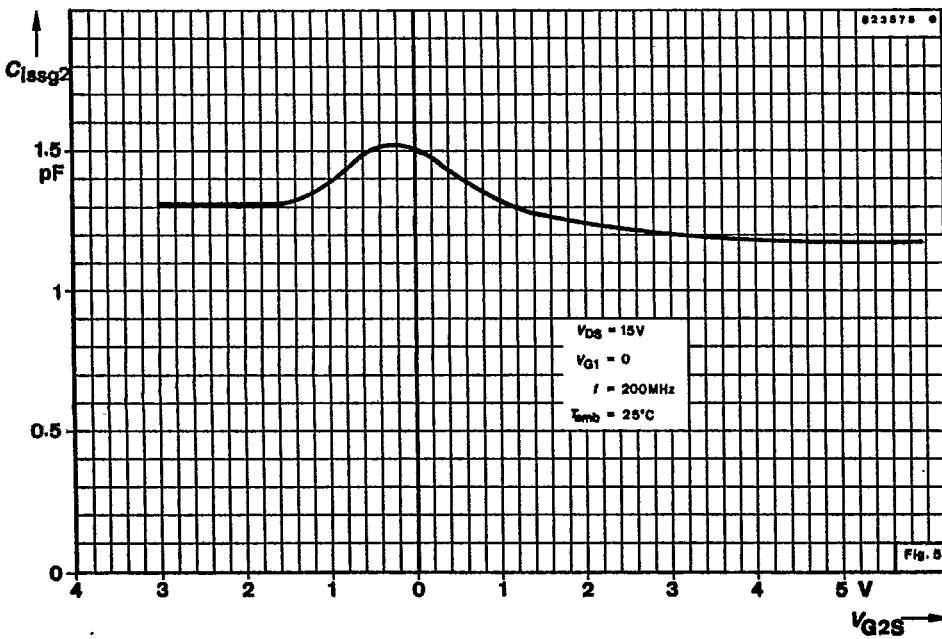
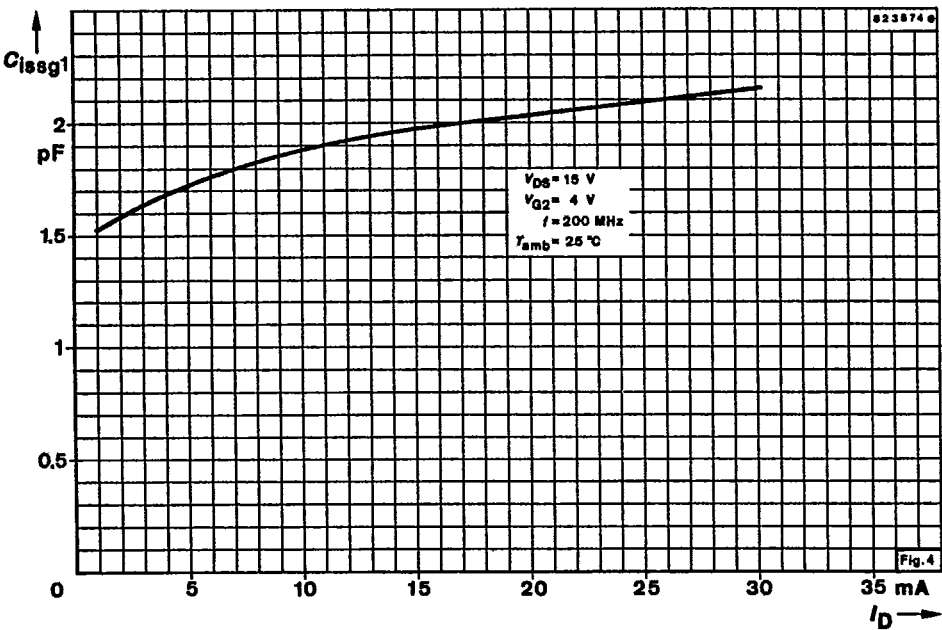
dB

 $V_{DS} = 15\text{ V}$, $I_D = 7\text{ mA}$, $V_{G2S} = 4\text{ V}$, $V_{G1S} = 0$ ¹⁾ G_2 and S grounded

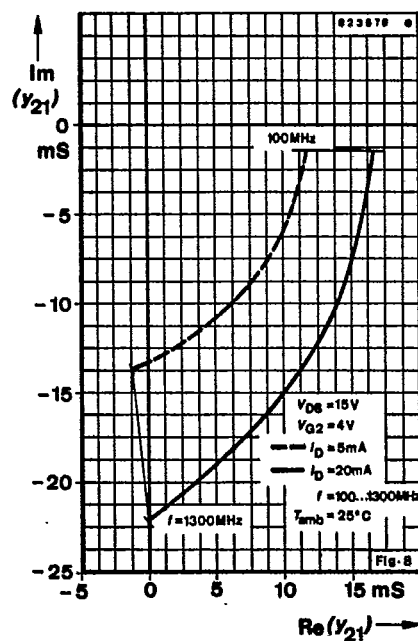
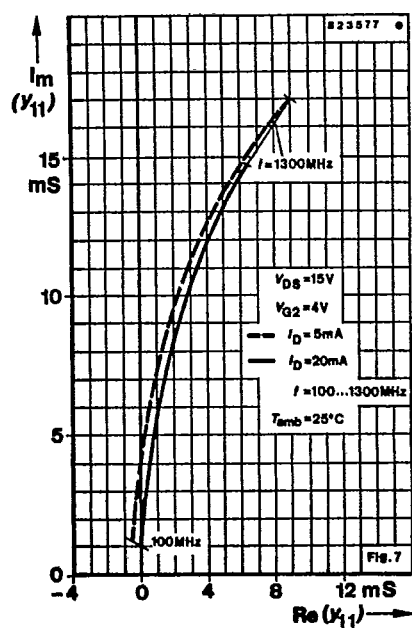
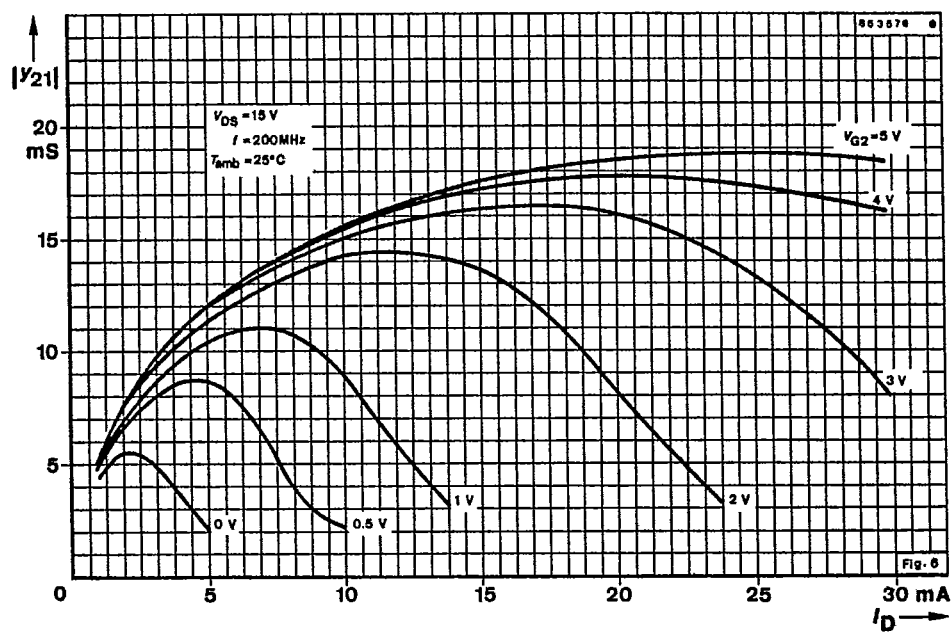
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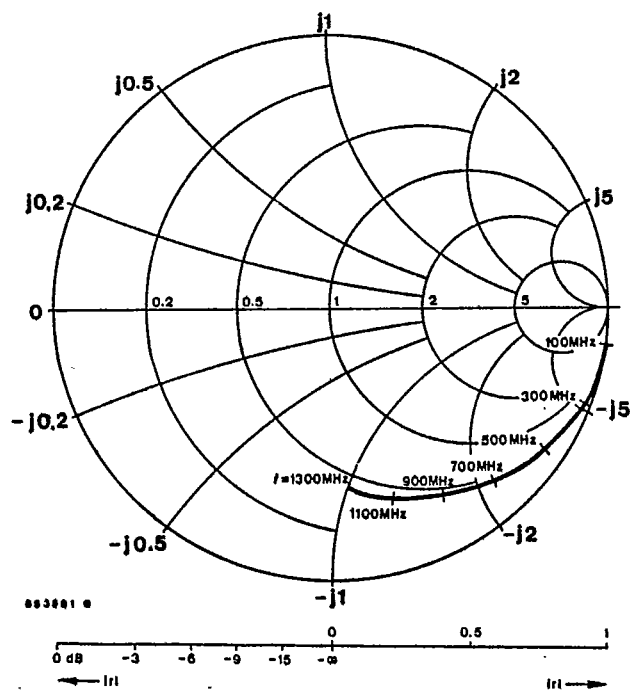
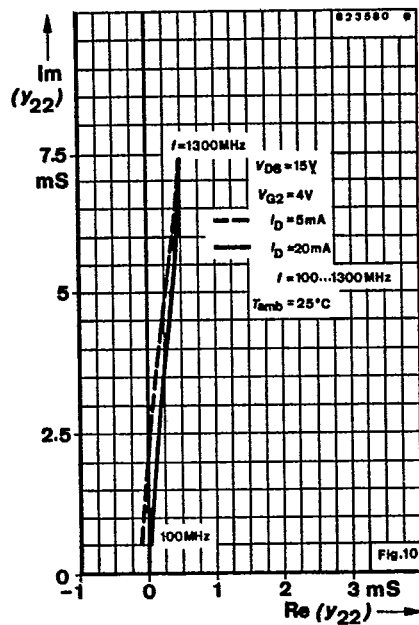
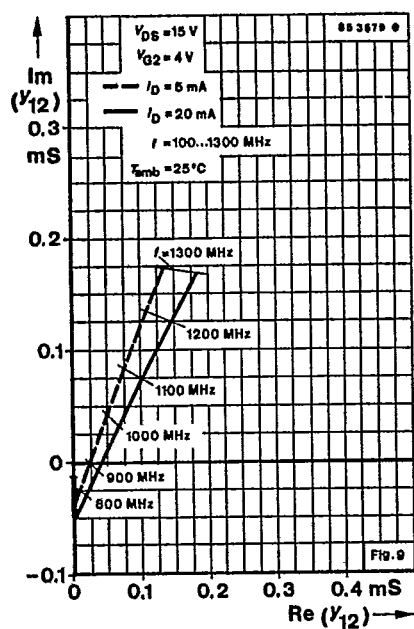


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S_{11}
 $I_D = 10 \text{ mA}$
 $V_{DS} = 15 \text{ V}$
 $V_{G2} = 4 \text{ V}$
 $Z_0 = 50 \Omega$
 $f = 100 \dots 1300 \text{ MHz}$
 $T_{amb} = 25^\circ \text{C}$

Fig. 11

T-31-25

BF 960

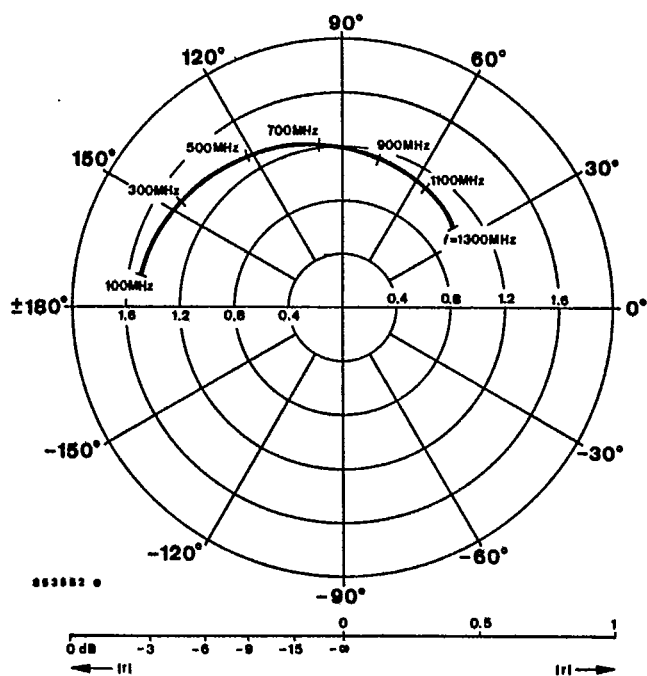
 S_{21} $Z_0 = 50\Omega$ $V_{DS} = 15V$ $V_{G2} = 4V$ $I_D = 10mA$ $f = 100...1300MHz$ $T_{amb} = 25^\circ C$

Fig.12

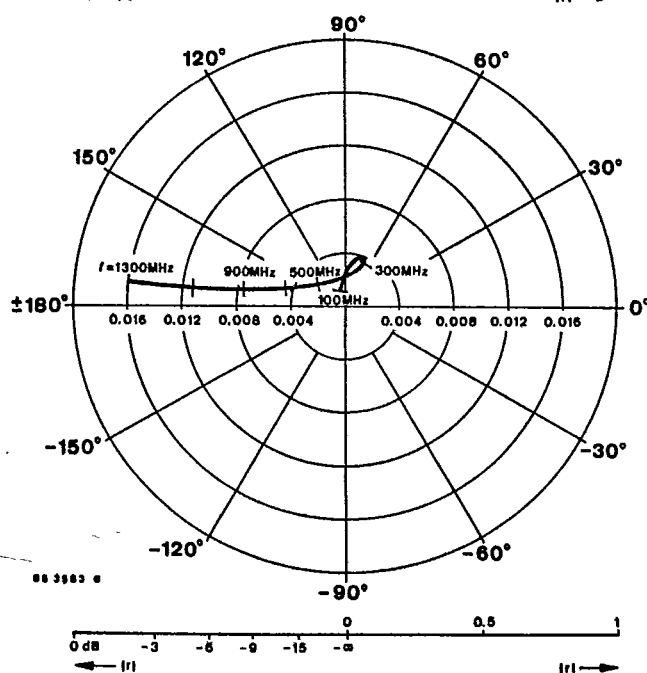
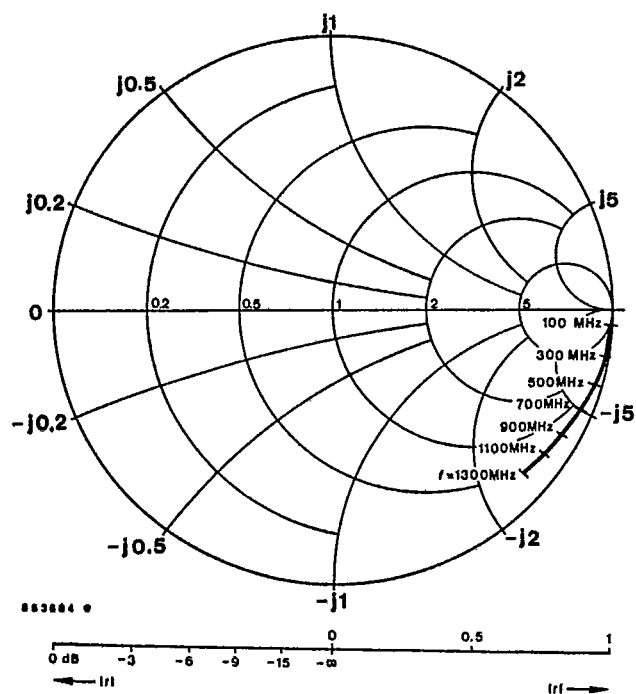
 S_{12} $Z_0 = 50\Omega$ $V_{DS} = 15V$ $V_{G2} = 4V$ $I_D = 10mA$ $f = 100...1300MHz$ $T_{amb} = 25^\circ C$

Fig.13

BF 960

T-3/-25

**S₂₂**

$I_D = 3 \dots 10 \text{ mA}$
 $V_{DS} = 15 \text{ V}$
 $V_{G2} = 4 \text{ V}$
 $Z_0 = 50 \Omega$
 $f = 100 \dots 1300 \text{ MHz}$
 $T_{amb} = 25^\circ \text{C}$

Fig.14

7. Taping and Reeling

T-91-20

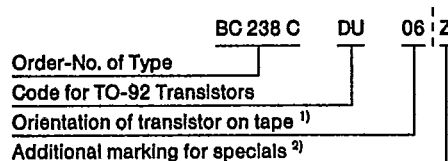
7.1. Taping of TO-92 Transistors

Standard reeling: Taped on reel, reeled together with a paper film.

7.1.1. Order Numbers

Add the taping-code to the order number.

Example:



¹⁾ 06 = View on flat side of transistor, view on gummed tape

05 = View on round side of transistor, view on gummed tape

²⁾ Additional marking "0": taping without paper film

Additional marking "Z": Zigzag folded tape in special box. Marking for orientation of transistor not necessary, because box can be opened on top or bottom

Example for order No.: BC 237 C DU Z

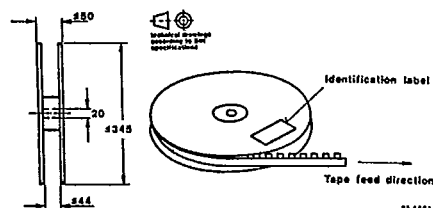


Fig. 7.1. Dimensions of reel in mm

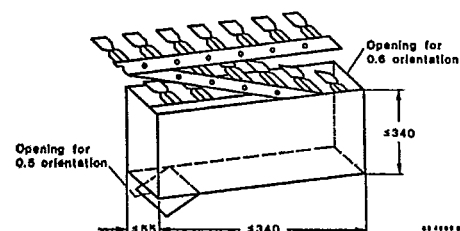


Fig. 7.2. Dimension of box for Zigzag folding in mm

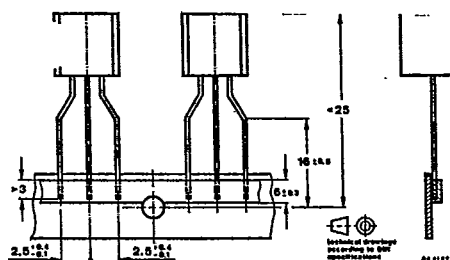


Fig. 7.3 Dimensions of tape in mm

7.1.2 Quantity of devices

1 000 devices per reel

2 000 devices per folded tape in special box.

7.2. Taped transistors in SOT 23 and SOT 143 case

7.2.1. Designation

a) Standard taping

Designation is attached with code GS 08 in case of standard taping. Example for normal version transistors as standard taped: BF 569-GS 08.

Example for R-version transistors as standard taped: BF 569 R-GS 08.

In case of standard taping, the transistor orientation on the tape is shown in Fig. 7.4 and Fig. 7.5.

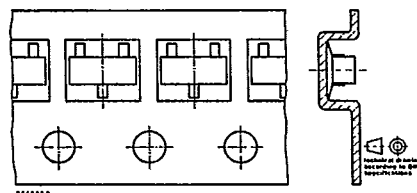


Fig. 7.4 Standard taped SOT 23

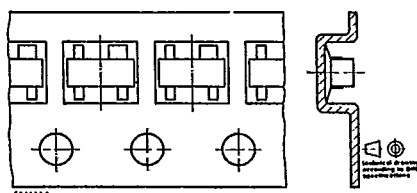


Fig. 7.5. Standard taped SOT 143

